

MBR1635 MBR1645

SCHOTTKY RECTIFIER

16 Amp

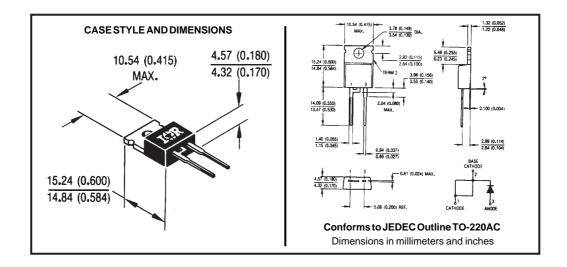
Major Ratings and Characteristics

Characteristics	MBR16	Units
I _{F(AV)} Rectangular waveform	16	А
V _{RRM}	35/45	V
I _{FSM} @ tp=5 µs sine	1800	А
V _F @16Apk, T _J =125°C	0.57	V
T _J	-65 to 150	°C

Description/Features

The MBR16.. Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150° C T operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



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Voltage Ratings

Part number	MBR1635	MBR1645	
V _R Max. DC Reverse Voltage (V)			
V _{RWM} Max. Working Peak Reverse Voltage (V)	35	45	

Absolute Maximum Ratings

	Parameters	MBR16	Units	Conditions
I _{F(AV)}	Max.AverageForwardCurrent	16	Α	@T _C =125°C,(RatedV _R)
I _{FSM}	Non-RepetitivePeakSurgeCurrent	1800	A	5μs Sine or 3μs Rect. pulse Following any rated load condition and with rated V _{RRM} applied
		150		Surgeappliedatratedloadconditionhalfwavesingle phase60Hz
I _{RRM}	PeakRepetitiveReverseSurgeCurrent	1.0	Α	2.0 µsec 1.0 KHz

Electrical Specifications

	Parameters	MBR16	Units	C	Conditions
V _{FM}	Max. Forward Voltage Drop (1)	0.63	V	@ 16A	T _J = 25 °C
		0.57	V	@ 16A	T _J = 125 °C
I _{RM}	Max. Instantaneus Reverse Current	0.2	mA	T _J = 25 °C	Pated DC voltage
	(1)	40	mA	T _J = 125 °C	Rated DC voltage
C _T	Max. Junction Capacitance	1400	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C	
L _s	Typical Series Inductance	8.0	nΗ	Measured from top of terminal to mounting plane	
dv/dt		1000	V/ µs		
	(Rated V _R)				

⁽¹⁾ Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

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	Parameters		MBR16	Units	Conditions	
T _J	Max.JunctionTemperatureRa	nge	-65to150	°C		
T _{stg}	Max.StorageTemperatureRar	nge	-65to175	°C		
R _{thJC}	Max.ThermalResistanceJunctoCase	tion	1.50	°C/W	DCoperation	
R _{thCS}	TypicalThermalResistance,C toHeatsink	ase	0.50	°C/W	Mountingsurface, smooth and greased	
wt	ApproximateWeight		2(0.07)	g(oz.)		
Т	MountingTorque	Min.	6(5)	Kg-cm		
		Max.	12(10)	(lbf-in)		
	Case Style		TO-220	AC	JEDEC	

^{*} For Additional Informations and Graphs, Please See the 18TQ Series

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